Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	3171	257/296.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 17:37
S2	655	257/300.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 10:05
S3	1907	257/306.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 10:06
S4	293	257/311.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 10:06
S5	336	257/297.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 10:38
S6	468	257/298.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 10:06
S7	468	257/298.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 10:48
S8	158	257/906.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 14:03

S9	2	"6730950".pn. and access	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 15:07
S10	14	lane-richard.inv.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 14:33
S13	0	"6730950".pn. and processor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 15:07
S14	1	"6730950".pn. and system	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 16:57
S15	1410	(access adj transistor) and processor and system	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 15:13
S16	536	(access adj transistor) and processor and system and "257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 15:14
S17	56	((access adj transistor) same processor same system) and "257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 16:23
S18	149	(memory near coupled near processor) and "257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 16:44

S19	26	(memory near connected near processor) and "257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 17:36
S20	0	"6730950".pn. and computer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 16:57
S21	0	"6730950".pn. and cpu	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 16:58
S22	1	"6730950".pn. and polysilicon	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:56
S23	0	(memory near (attached or joined or tied) near processor) and "257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 17:36
S24	0	(memory near (afixed) near processor) and "257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 17:37
S25	162	257/296.ccls. and processor and system	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 17:40
S26	30	257/296.ccls. and (processor near system)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:02

S28	11	content adj addressable adj memory adj portion	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:45
S29	96	(content adj addressable adj memory) and (access adj transistor) and capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:52
S30	97	(cam) and (access adj transistor) and capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:49
S31	10	(content adj addressable adj memory) and (access adj transistor) and capacitor and "257"/$.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:52
S32	0	"6730950".pn. and cam	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:56
S33	0	"6730950".pn. and addressable	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 18:57
S34	1	"6730950".pn. and content	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 19:06
S35	2	"20010045589".pn. and cam	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 19:08

S36	2	"20010045589".pn. and content	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 19:10
S37	0	"20010045589".pn. and (acess adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 19:10
S38	1	"20010045589".pn. and (access adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:01
S40	203	((surface adj area) near capacitor) and (access adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:03
S41	25	((surface adj area) near (lower adj electrode)) and (access adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:08
S42	14	((surface adj area) near (bottom adj electrode)) and (access adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:12
S43	10	((surface adj area) near (bottom adj plate)) and (access adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:16
S44	0	((surface adj area) near (lower adj plate)) and (access adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:17

S45	4	((surface adj area) near ((first or second) adj plate)) and (access adj transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:18
S46	143	surface adj area adj capacitor adj plate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:25
S47	280	surface adj area adj capacitor adj electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:33
S48	1	capacitor adj electrode adj dimension	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:35
S49	4	(capacitor adj electrode) near nm	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:36
S50	2	(capacitor adj plate) near nm	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:37
S51	5	(cell adj plate) near nm	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:42
S52	0	((first adj conductive adj plug) near polysilicon) and ((second adj conductive adj plug) near metal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:44

S53	3	((first adj conductive adj plug) with polysilicon) and ((second adj conductive adj plug) with metal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:46
S54	7	((first adj conductive adj plug) same polysilicon) and ((second adj conductive adj plug) same metal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:52
S55	1	conductive adj plugs adj different adj material	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:56
S56	0	conductive adj vias adj different adj material	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:55
S57	0	conductive adj holes adj different adj material	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 20:55
S58	4	conductive near plugs near different near material	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:05
S59	2	distance adj between adj conductive adj plugs	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:10
S60	5	distance near (conductive adj plugs)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:10

S61	2	distance near (first adj conductive adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:08
S62	17	distance with (first adj conductive adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:08
S63	2	distance adj between adj conductive adj posts	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:10
S64	0	distance near (conductive adj posts)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:10
S65	50	distance with (conductive adj posts)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:11
S66	0	distance with (conductive adj posts) with nm	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:22
S67	0	(polysilicon adj conductive adj posts)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:22
S68	47	(polysilicon adj conductive adj plugs)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:27

S69	141	(metal adj conductive adj plugs)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/18 21:30
S70	19	(tungsten adj conductive adj plugs)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 17:08
S71	106	(surface adj area) near (electrode adj plate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 12:44
S72	45	(dimensions adj capacitor adj (electrode or plate or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 12:49
S73	96	(size adj capacitor adj (electrode or plate or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 13:04
S75	26	(size adj (electrode or plate or conductor)) near capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 13:06
S76	227	(area adj (electrode or plate or conductor)) near capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:22
S77	1034	(area adj capacitor adj (electrode or plate or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 13:06

S78	13	(area adj (conductive)) near capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:23
S79	2	(area adj (conducting)) near capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:24
S80	0	(area adj (conduction)) near capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:24
S81	10	(area adj (metal)) near capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:27
S82	1	conductive adj plug adj separation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:28
S83	1	metal adj plug adj separation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:28
S84	167	plug adj separation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:35
S85	160	distance adj between adj contact adj (hole or via)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:42

S86	286	distance adj between adj plugs	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 14:49
S87	163	spacing adj between adj plugs	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:16
S88	28	(width or length) adj between adj plugs	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:03
S89	1	conductive adj plug adj spacing	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:07
S90	29	contact adj hole adj spacing	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:15
S91	2	contact adj plug adj spacing	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:31
S92	140	spacing adj between adj interconnects	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:16
S93	187	distance adj between adj interconnects	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:16

S94	2	contact adj plug adj pitch	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:42
S95	0	conductive adj plug adj pitch	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:32
S96	35	plug adj pitch	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:32
S97	19	contact adj hole adj pitch	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:45
S98	0	conductive adj hole adj pitch	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 15:45
S99	108	through adj hole adj pitch	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 16:00
S100	2	"6444520".pn. and different	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 16:00
S101	0	(tungsten adj conductive adj post)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 17:09

S10 2	0	(tungsten adj conductive adj holes)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 17:08
S10 3	0	(tungsten adj conductive adj hole)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 17:08
S10 4	1	(tungsten adj conductive adj via)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 17:08
S10 6	0	(tungsten adj plugs) and capcitor and mosfet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 17:10
S10 7	142	(tungsten adj plugs) and capacitor and mosfet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:08
S10 8	3	(tungsten adj plugs) with capacitor with mosfet	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 17:14
S10 9	47	(capacitor adj (electrode or plate)) near (plug or post)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:11
S11 1	0	(capacitor adj (electrode or plate)) with ((plug or post) near distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:13

S11 2	6	(capacitor adj (electrode or plate)) and ((plug or post) near distance)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:13
S11 3	1	(capacitor adj (electrode or plate)) and ((plug or post) near pitch)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:14
S11 4	45	(capacitor adj (electrode or plate)) and ((plug or post) near (width or length))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:19
S11 5	0	(capacitor adj (electrode or plate)) and (closest adj distance adj between adj (plug or post or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:20
S11 6	0	(closest adj distance adj between adj (plug or post or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:20
S11 7	0	(closest near distance near between near (plug or post or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:21
S11 8	158	(closest with distance with between with (plug or post or conductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:33
S11 9	1	"4903110".pn. and area	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:44

S12 0	14	distance near (first adj plug) near (second adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:46
S12 1	0	distance near (first adj conductive adj plug) near (second adj conductive adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:46
S12 2	6	distance with (first adj conductive adj plug) with (second adj conductive adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:47
S12 3	17	distance same (first adj conductive adj plug) same (second adj conductive adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:49
S12 4	2	pitch same (first adj conductive adj plug) same (second adj conductive adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:51
S12 5	23	(width or length) same (first adj conductive adj plug) same (second adj conductive adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:56
S12 6	132	(width or length) same (first adj via) same (second adj via)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:57
S12 7	3	(width or length) same (first adj via) same (second adj via) same nm	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 18:56

S128	66	(width or length) with (first adj via) with (second adj via)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:03
S129	87	(distance) with (first adj plug) with (second adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:06
S130	8	(spacing) with (first adj plug) with (second adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:06
S131	5	(pitch) with (first adj plug) with (second adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:07
S132	21	(separation) with (first adj plug) with (second adj plug)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/20 19:07